## NSN 5961-00-057-6413

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-057-6413 **Inclosure Material:** Metal **Overall Length:** 1.750 inches **Overall Diameter:** 1.063 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.219 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakdown voltage, collector-to-base, emitter open and 150.0 breakdown voltage, collector-to-emitter, base open and 15.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release3577 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

## **NSN 5961-00-057-6413** Transistor - Page 2 of 2



Fiig:

A110a0